## VS-6EWX06FNHM3

**Vishay Semiconductors** 

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## Hyperfast Rectifier, 6 A FRED Pt<sup>®</sup>



DPAK (TO-252AA)

| PRIMARY CHARACTERISTICS          |                 |  |  |  |  |
|----------------------------------|-----------------|--|--|--|--|
| I <sub>F(AV)</sub>               | 6 A             |  |  |  |  |
| V <sub>R</sub>                   | 600 V           |  |  |  |  |
| V <sub>F</sub> at I <sub>F</sub> | 1.65 V          |  |  |  |  |
| t <sub>rr</sub> (typ.)           | 14 ns           |  |  |  |  |
| T <sub>J</sub> max.              | 175 °C          |  |  |  |  |
| Package                          | DPAK (TO-252AA) |  |  |  |  |
| Circuit configuration            | Single          |  |  |  |  |

#### FEATURES

- Hyperfast recovery time, extremely low Q<sub>rr</sub>
- 175 °C maximum operating junction temperature
- For PFC CCM operation
- Low forward voltage drop
- Low leakage current
- AEC-Q101 qualified
- Meets JESD 201 class 2 whisker test
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

#### **DESCRIPTION / APPLICATIONS**

State of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC boost stage in the AC/DC section of SMPS inverters or as freewheeling diodes. Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

| ABSOLUTE MAXIMUM RATINGS                    |                                   |   |             |       |  |  |
|---|-----------------------------------|---|-------------|-------|--|--|
| PARAMETER                                   | SYMBOL                            | TEST CONDITIONS   | VALUES      | UNITS |  |  |
| Peak repetitive reverse voltage             | V <sub>RRM</sub>                  |   | 600         | V     |  |  |
| Average rectified forward current           | I <sub>F(AV)</sub>                | T <sub>C</sub> = 136 °C                                     | 6           |       |  |  |
| Non-repetitive peak surge current           | I <sub>FSM</sub>                  | T <sub>J</sub> = 25 °C                                      | 50          | А     |  |  |
| Peak repetitive forward current             | I <sub>FM</sub>                   | $T_{C} = 136 \ ^{\circ}C, f = 20 \ \text{kHz}, d = 50 \ \%$ | 12          |       |  |  |
| Operating junction and storage temperatures | T <sub>J</sub> , T <sub>Stg</sub> |   | -65 to +175 | °C    |  |  |

| <b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 $^{\circ}$ C unless otherwise specified) |                                     |   |      |      |      |       |
|--|-------------------------------------|---|------|------|------|-------|
| PARAMETER  | SYMBOL                              | TEST CONDITIONS                                 | MIN. | TYP. | MAX. | UNITS |
| Breakdown voltage,<br>blocking voltage   | V <sub>BR</sub> ,<br>V <sub>R</sub> | I <sub>R</sub> = 100 μA                         | 600  | -    | -    | v     |
| Forward voltage  | V                                   | I <sub>F</sub> = 6 A                            | -    | 2.50 | 3.1  | v     |
| Forward voltage  | V <sub>F</sub>                      | I <sub>F</sub> = 6 A, T <sub>J</sub> = 150 °C   | -    | 1.65 | 1.9  |       |
| Reverse leakage current  | 1_                                  | $V_{\rm R} = V_{\rm R}$ rated                   | -    | -    | 20   |       |
| neverse leakage current  | IR                                  | $T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$ | -    | -    | 250  | μA    |
| Junction capacitance   | CT                                  | V <sub>R</sub> = 600 V                          | -    | 3.5  | -    | pF    |
| Series inductance  | L <sub>S</sub>                      | Measured lead to lead 5 mm from package body    | -    | 8    | -    | nH    |





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1



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| <b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_J = 25$ °C unless otherwise specified) |                  |   |   |      |      |       |      |  |
|---|------------------|---|---|------|------|-------|------|--|
| PARAMETER   | SYMBOL           | TEST CO   | MIN.  | TYP. | MAX. | UNITS |      |  |
| Reverse recovery time t <sub>rr</sub>   |                  | $I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 10$  | $I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 100 \text{ A}/\mu\text{s}, \text{ V}_R = 30 \text{ V}$ |      | 14   | 21    |      |  |
|   |                  | $I_F = 1 \text{ A}, \text{ d}_F/\text{d}t = 50 \text{ A}/\mu\text{s}, \text{ V}_R = 30 \text{ V}$ |   | -    | 16   | -     |      |  |
|   | ۲r               | T <sub>J</sub> = 25 °C  |   | -    | 19   | -     | A nC |  |
|   |                  | T <sub>J</sub> = 125 °C   | $\label{eq:IF} \begin{array}{l} I_F=6~A\\ dI_F/dt=200~A/\mu s\\ V_R=390~V \end{array}$              | -    | 27   | -     |      |  |
| Peak recovery current I <sub>RR</sub>   | I <sub>RRM</sub> | T <sub>J</sub> = 25 °C  |   | -    | 3.0  | -     |      |  |
|   |                  | T <sub>J</sub> = 125 °C   |   | -    | 4.0  | -     |      |  |
| Reverse recovery charge   | Q <sub>rr</sub>  | T <sub>J</sub> = 25 °C  |   | -    | 28   | -     |      |  |
|   |                  | T <sub>J</sub> = 125 °C   |   | -    | 57   | -     |      |  |

| THERMAL - MECHANICAL SPECIFICATIONS             |                                   |                            |      |      |       |       |
|---|-----------------------------------|----------------------------|------|------|-------|-------|
| PARAMETER                                       | SYMBOL                            | TEST CONDITIONS            | MIN. | TYP. | MAX.  | UNITS |
| Maximum junction and storage temperature range  | T <sub>J</sub> , T <sub>Stg</sub> |                            | -65  | -    | 175   | °C    |
| Thermal resistance,<br>junction to case per leg | R <sub>thJC</sub>                 |                            | -    | -    | 3     | °C/W  |
| Approximate weight                              |                                   |                            |      | 0.3  |       | g     |
|   |                                   |                            |      | 0.01 |       | oz.   |
| Marking device                                  |                                   | Case style DPAK (TO-252AA) |      | 6EWX | 06FNH |       |

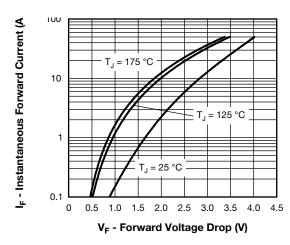
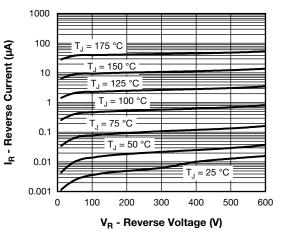
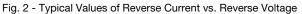
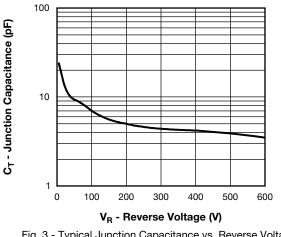


Fig. 1 - Typical Forward Voltage Drop Characteristics







2

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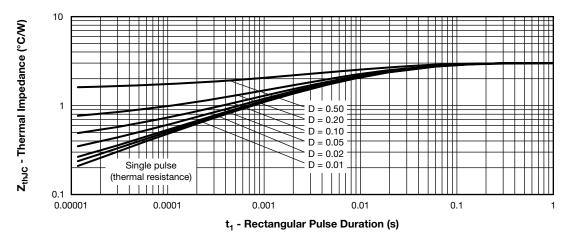
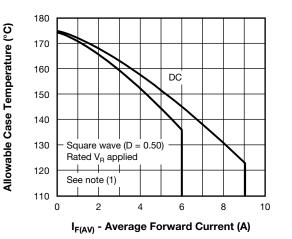


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics



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Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

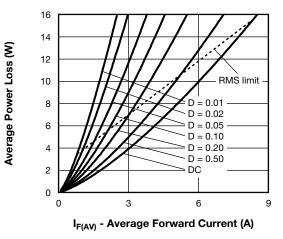


Fig. 6 - Forward Power Loss Characteristics

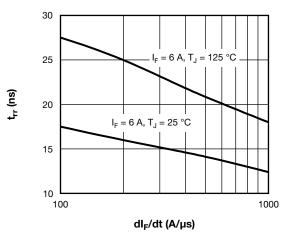
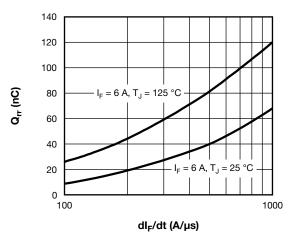


Fig. 7 - Typical Reverse Recovery Time vs.  $dI_F/dt$ 





### Note

- <sup>(1)</sup> Formula used:  $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$ ;
- $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \ x \ \mathsf{V}_{\mathsf{FM}} \ at \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \ x \ \mathsf{I}_{\mathsf{R}} \ (1 \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ at \ \mathsf{V}_{\mathsf{R1}} = \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

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3

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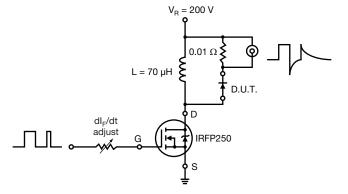


Fig. 9 - Reverse Recovery Parameter Test Circuit

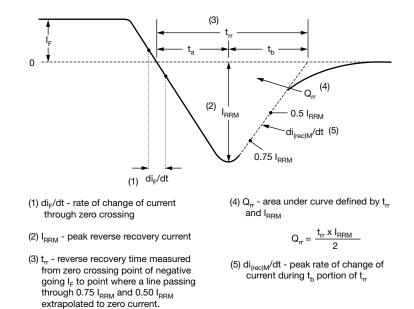


Fig. 10 - Reverse Recovery Waveform and Definitions

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**ORDERING INFORMATION TABLE** 

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| Device code | vs-              | 6                        | E  | w   | x                                 | 06      | FN      | TRL      | Н         | М3        |
|-------------|------------------|--------------------------|--|---|-----------------------------------|---------|---------|----------|-----------|-----------|
|             | 1                | 2                        | 3  | 4   | 5                                 | 6       | 7       | 8        | 9         | 10        |
|             | 1<br>2<br>3      | - Cu<br>- Cir            | shay Sen<br>rrent rati<br>cuit conf<br>= single c  | ng (6 =<br>iguratior                          | 6 A)                              | oduct   |         |          |           |           |
|             | 4                | - Pa                     | ckage id<br>= D-PAK  | entifier:                                     |                                   |         |         |          |           |           |
|             | 5<br>6<br>7<br>8 | - Vo<br>- FN             | X = hyperfast recovery time<br>Voltage rating (06 = 600 V)<br>FN = TO-252AA<br>• None = tube |   |                                   |         |         |          |           |           |
|             | 9                | • 1<br>• 1<br>• 1<br>- H | R = tape<br>RL = tap<br>RR = tap<br>AEC-Q  | e and ree<br>be and re<br>be and r<br>101 qua | eel (left<br>eel (righ<br>alified |         | -       |          |           |           |
|             | 10               |                          | vironmer<br>5 = halog  | -   |                                   | complia | nt, and | terminat | tions lea | ad (Pb)-i |

| ORDERING INFORMATION (Example) |                  |                        |                         |  |  |  |  |
|--------------------------------|------------------|------------------------|-------------------------|--|--|--|--|
| PREFERRED P/N                  | QUANTITY PER T/R | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION   |  |  |  |  |
| VS-6EWX06FNHM3                 | 75               | 3000                   | Antistatic plastic tube |  |  |  |  |
| VS-6EWX06FNTRHM3               | 2000             | 2000                   | 13" diameter reel       |  |  |  |  |
| VS-6EWX06FNTRRHM3              | 3000             | 3000                   | 13" diameter reel       |  |  |  |  |
| VS-6EWX06FNTRLHM3              | 3000             | 3000                   | 13" diameter reel       |  |  |  |  |

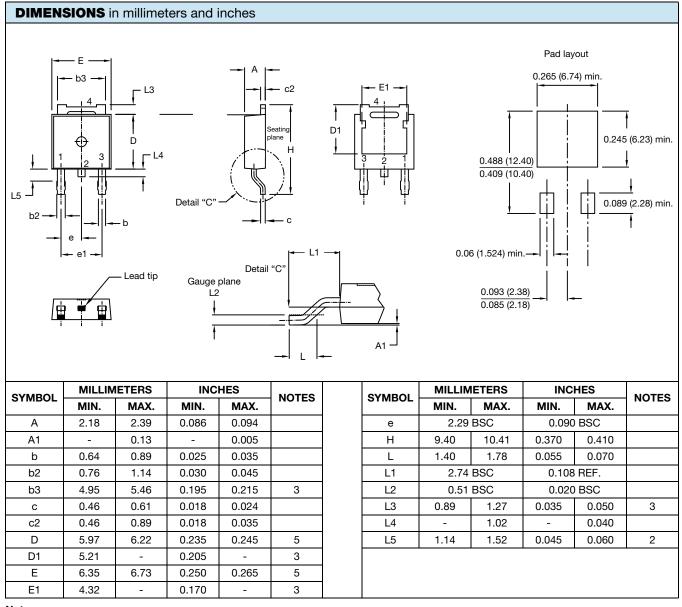
| LINKS TO RELATED DOCUMENTS |                          |  |  |  |  |
|----------------------------|--------------------------|--|--|--|--|
| Dimensions                 | www.vishay.com/doc?95519 |  |  |  |  |
| Part marking information   | www.vishay.com/doc?95518 |  |  |  |  |
| Packaging information      | www.vishay.com/doc?95033 |  |  |  |  |

### **Outline Dimensions**



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## DPAK (TO-252AA)



#### Notes

<sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994

<sup>(2)</sup> Lead dimension uncontrolled in L5

<sup>(3)</sup> Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad

<sup>(4)</sup> Dimensions D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

<sup>(5)</sup> Outline conforms to JEDEC<sup>®</sup> outline TO-252AA



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